

PATENT ABSTRACTS OF JAPAN

(11)Publication number : 2001-144155

(43)Date of publication of application : 25.05.2001

(51)Int.Cl.

H01L 21/66
G01B 15/00
G01N 23/227

(21)Application number : 11-327997

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(22)Date of filing : 18.11.1999

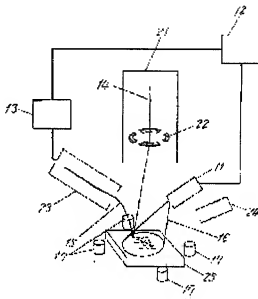
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(54) SEMICONDUCTOR ANALYSIS DEVICE AND ANALYSIS METHOD

(57)Abstract:

PROBLEM TO BE SOLVED: To solve the problem of inability to detect the potential difference among P-N junctions due to the charging of an interface level in a conventional Auger electron spectroscopy.

SOLUTION: A constitution, where a function 11 for irradiating a sample surface with a light having energy larger than the band gap of a sample and smaller than the work function of the sample and functions 12 and 13 modulating light intensity and detecting the fluctuation components of Auger electron intensity synchronized with light intensity added in addition to the function of a conventional Auger electron spectral device are added, is arranged. Plural photodetectors, which adjust an optical axis, are arranged near the optical axis of light irradiating the sample surface.



LEGAL STATUS

[Date of request for examination]

[Date of sending the examiner's decision of rejection]

[Kind of final disposal of application other than the examiner's decision of rejection or application converted registration]

[Date of final disposal for application]

[Patent number]

[Date of registration]

[Number of appeal against examiner's decision of rejection]

[Date of requesting appeal against examiner's decision of rejection]

[Date of extinction of right]